Visible High Power Laser Diode



ODE-208-601D (Z)

Rev.4 Jan. 2003

Description

The HL6738MG is a $0.68~\mu m$ band AlGaInP laser diode (LD) with a multi-quantum well (MQW) structure. It is suitable as a light source for large capacity optical disc memories and various other types of optical equipment.

Hermetic sealing of the small package (\$\phi\$ 5.6 mm) assures high reliability.

Application

- Optical disc memories
- Optical equipment

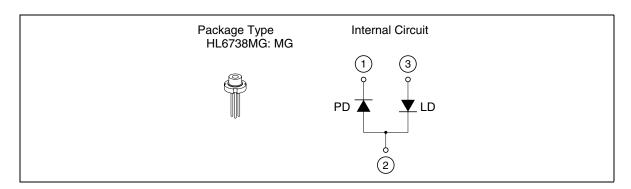
Features

High output power : 35 mW (CW)
 Visible light output : λp = 680 to 695 nm

• Small package : \$\phi\$ 5.6 mm

• Low astigmatism : $6 \mu m \text{ Typ } (P_0 = 5 \text{ mW})$

• Single longitudinal mode





Absolute Maximum Ratings

 $(T_c = 25^{\circ}C)$

Item	Symbol	Value	Unit	
Optical output power	P _o	35	mW	
Pulse optical output power	P _{O(pulse)}	50 *	mW	
Laser diode reverse voltage	V _{R(LD)}	2	V	
Photo diode reverse voltage	V _{R(PD)}	30	V	
Operating temperature	Topr	-10 to +70	°C	
Storage temperature	Tstg	-40 to +85	°C	

Note: Pulse condition: Pulse width = 100 ns, duty = 50%

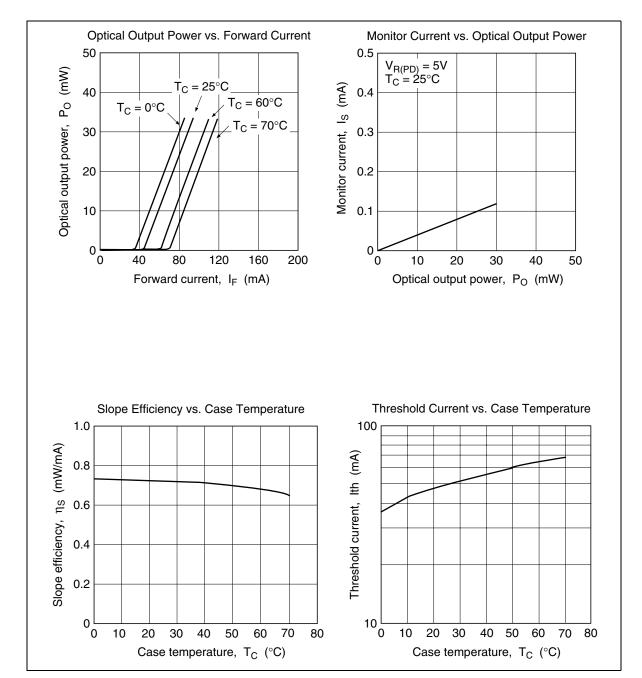
Optical and Electrical Characteristics

 $(T_c = 25^{\circ}C)$

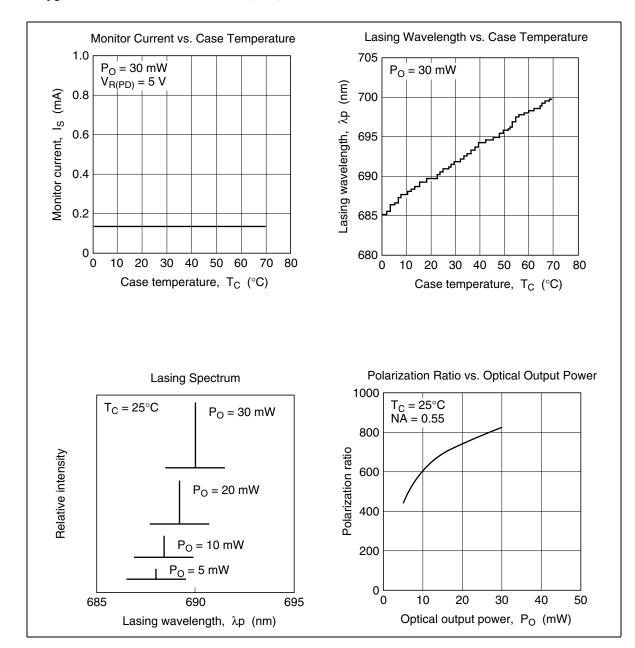
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Threshold current	Ith	30	45	70	mA	_
Operating voltage	V _{OP}	2.1	2.5	2.8	V	P _o = 30 mW
Slope efficiency	ης	0.5	0.7	0.9	mW/mA	18(mW) / (I _(24mW) – I _(6mW))
Beam divergence parallel to the junction	θ//	7	8.5	10.5	deg.	P _o = 30 mW
Beam divergence parpendicular to the junction	θ⊥	17	19	23	deg.	P _o = 30 mW
Asitgmatism	A _s	_	6	_	μm	$P_0 = 5 \text{ mW}, \text{ NA} = 0.55$
Lasing wavelength	λр	680	690	695	nm	P _o = 30 mW
Monitor current	I _s	0.02	0.1	0.45	mA	$P_{O} = 30 \text{ mW}, V_{R(PD)} = 5 \text{ V}$



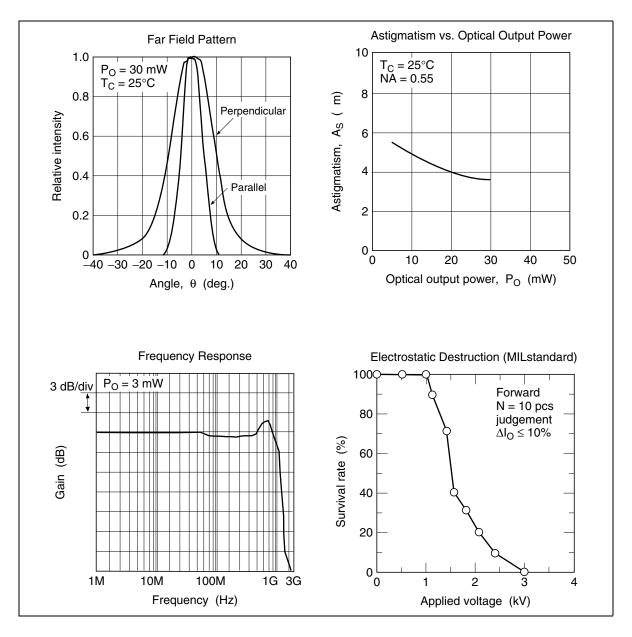
Typical Characteristic Curves



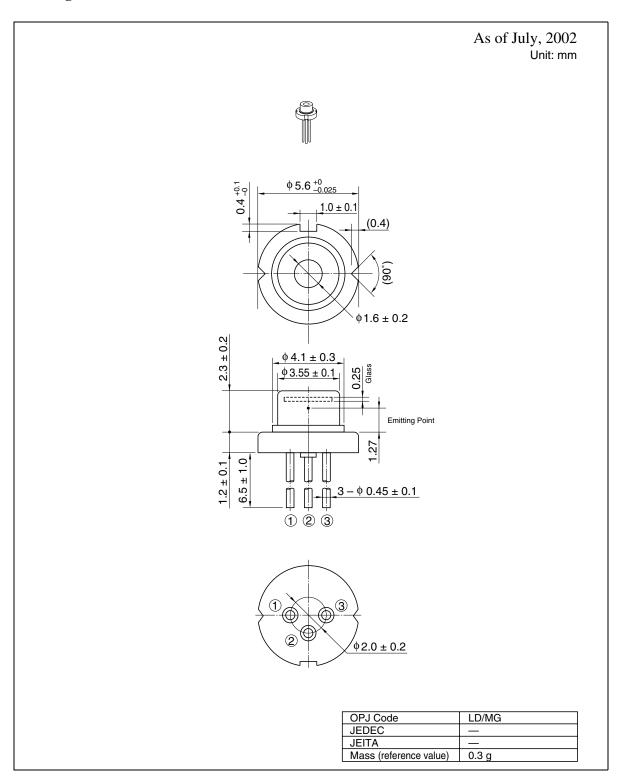
Typical Characteristic Curves (cont)



Typical Characteristic Curves (cont)



Package Dimensions





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